



#### DMN3009LFVQ

PowerDI3333-8 (Type UX)

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C
	5.5mΩ @ V <sub>GS</sub> = 10V	60A
30V	9.0mΩ @ V <sub>GS</sub> = 4.5V	50A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

# Features and Benefits

- Low R<sub>DS(ON)</sub>—Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products

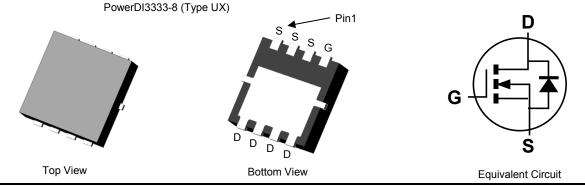
30V N-CHANNEL ENHANCEMENT MODE MOSFET

- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DMN3009LFVQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3009LFVQ-7	PowerDI3333-8 (Type UX)	2000/Tape & Reel
DMN3009LFVQ-13	PowerDI3333-8 (Type UX)	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



<u>SH1</u>= Product Type Marking Code <u>YY</u>WW = Date Code Marking <u>YY</u> = Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)

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### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	30	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 7) $V_{GS}$ = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	60 50	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	90	А
Maximum Continuous Body Diode Forward Current (Note 7)	Is	60	А	
Avalanche Current, L = 0.1mH (Note 8)	I <sub>AS</sub>	33	A	
Avalanche Energy, L = 0.1mH (Note 8)	E <sub>AS</sub>	58	mJ	

### Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	1.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>OJA</sub>	126	°C/W	
Total Power Dissipation (Note 6)		PD	2.0	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>OJA</sub>	62	°C/W	
Thermal Resistance, Junction to Case (Note 7)		Rejc	3.5	C/w	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

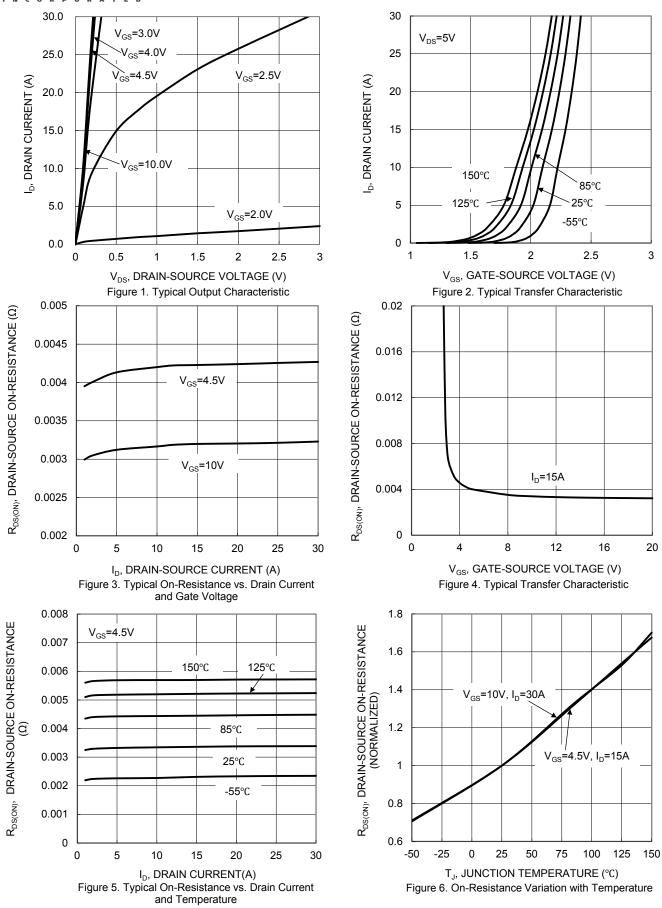
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	—	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		—	3.5	5.5	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		4.6	9.0	11152	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 15A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A	
DYNAMIC CHARACTERISTICS (Note 10)	•						
Input Capacitance	C <sub>iss</sub>	—	2,000	—	pF		
Output Capacitance	Coss	—	315	—	pF	−V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, −f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	247	—	pF		
Gate Resistance	Rg	_	2.2	_	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	—	20	—	nC	_	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	42	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	4.7	_	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 15A	
Gate-Drain Charge	Q <sub>gd</sub>	_	7.4	_	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.9	—	ns	$V_{DD}$ = 15V, $V_{GS}$ = 10V, $R_{G}$ = 3.3 $\Omega$ , , $I_{D}$ = 15A	
Turn-On Rise Time	t <sub>R</sub>	_	4.1		ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>		31		ns		
Turn-Off Fall Time	tF		15		ns		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	—	15	—	ns	I <sub>F</sub> = 15A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	—	6.0	—	nC		

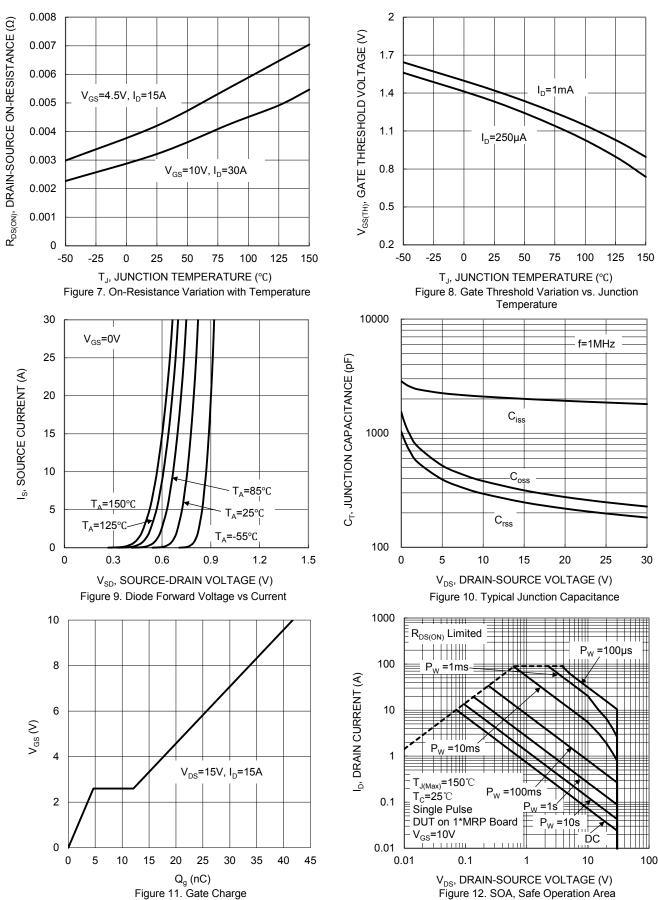
Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.



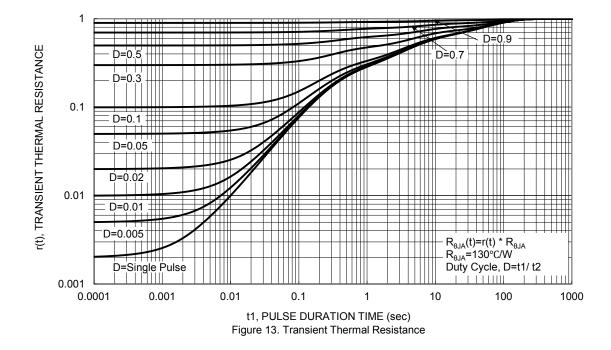
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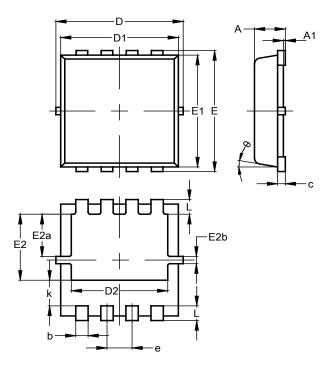






## **Package Outline Dimensions**

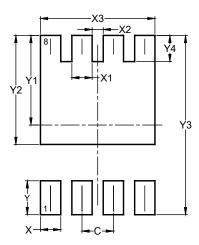
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8 (Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
E	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E2a	0.95	1.35	1.15		
E2b	0.10	0.30	0.20		
е	0.65 BSC				
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.370			
Y	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			
Y4	0.540			



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